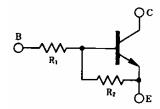


COMPOUND TRANSISTOR HD1 SERIES

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

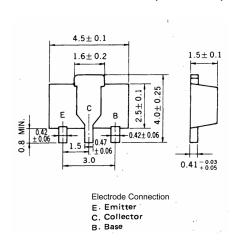
- High current drives such as IC outputs and actuators available
- · On-chip bias resistor
- · Low power consumption during drive



HD1 SERIES LISTS

Products	Marking	R ₁ (kΩ)	R ₂ (kΩ)
HD1A3M	LP	1.0	1.0
HD1F3P	LQ	2.2	10
HD1L3N	LR	4.7	10
HD1A4M	LS	10	10
HD1L2Q	LT	0.47	4.7
HD1F2Q	LU	0.22	2.2
HD1A4A	LX	-	10

PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	80	V
Collector to emitter voltage	VCEO	60	V
Emitter to base voltage	V _{EBO}	10	V
Collector current (DC)	Ic(DC)	1.0	Α
Collector current (Pulse)	I _{C(pulse)} Note1	2.0	Α
Base current (DC)	I _{B(DC)}	0.02	Α
Total power dissipation	P _T Note2	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	−55 to +150	°C

Notes 1. PW \leq 10 ms, duty cycle \leq 50 %

2. When $0.7 \text{ mm} \times 16 \text{ cm}^2$ ceramic board is used

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HD1A3M ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = 60 V, I _E = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	80			1
DC current gain	hfE2 Note	Vce = 2.0 V, Ic = 0.5 A	200			1
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			1
Low level output voltage	Vol. Note	V _{IN} = 5.0 V, Ic = 0.4 A			0.35	V
Low level input voltage	V _{IL} Note	Vcε = 5.0 V, Ic = 100 μA			0.3	V
Input resistance	R ₁		0.7	1.0	1.3	kΩ
E-to-B resistance	R ₂		0.7	1.0	1.3	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1F3P

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	hfE1 Note	Vce = 2.0 V, Ic = 0.1 A	200	630		-
DC current gain	hFE2 Note	Vce = 2.0 V, Ic = 0.5 A	300	780		-
DC current gain	hfE3 Note	Vce = 2.0 V, Ic = 1.0 A	200	430		-
Low level output voltage	Vol. Note	V _{IN} = 5.0 V, Ic = 0.3 A		0.12	0.3	٧
Low level input voltage	V _{IL} Note	$V_{CE} = 5.0 \text{ V}, I_{C} = 100 \ \mu\text{A}$		0.5	0.3	٧
Input resistance	R ₁		1.54	2.2	2.86	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1L3N

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	200			-
DC current gain	h _{FE2} Note	Vce = 2.0 V, Ic = 0.5 A	300			ı
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			ı
Low level output voltage	Vol. Note	$V_{IN} = 5.0 \text{ V}, \text{ Ic} = 0.2 \text{ A}$			0.2	٧
Low level input voltage	V _{IL} Note	$V_{CE} = 5.0 \text{ V, Ic} = 100 \mu\text{A}$			0.3	٧
Input resistance	R ₁		3.29	4.7	6.11	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %



HD1A4M ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	200			-
DC current gain	hfE2 Note	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	Vol. Note	V _{IN} = 5.0 V, Ic = 0.1 A			0.2	V
Low level input voltage	V _{IL} Note	Vcε = 5.0 V, Ic = 100 μA			0.3	V
Input resistance	R ₁		7	10	13	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1L2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	200			-
DC current gain	h _{FE2} Note	Vce = 2.0 V, Ic = 0.5 A	300			_
DC current gain	hfE3 Note	Vce = 2.0 V, Ic = 1.0 A	200			-
Low level output voltage	Vol. Note	V _{IN} = 5.0 V, Ic = 0.8 A			0.5	٧
Low level input voltage	V _{IL} Note	Vcε = 5.0 V, Ic = 100 μA			0.3	V
Input resistance	R ₁		329	470	611	Ω
E-to-B resistance	R ₂		3.29	4.7	6.11	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HD1F2Q ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	100			-
DC current gain	h _{FE2} Note	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	h _{FE3} Note	Vce = 2.0 V, Ic = 1.0 A	200			ı
Low level output voltage	Vol. Note	$V_{IN} = 5.0 \text{ V}, \text{ Ic} = 0.8 \text{ A}$			0.5	٧
Low level input voltage	V _{IL} Note	$V_{CE} = 5.0 \text{ V, Ic} = 100 \mu\text{A}$			0.3	٧
Input resistance	R ₁		154	220	286	Ω
E-to-B resistance	R ₂		1.54	2.2	2.86	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

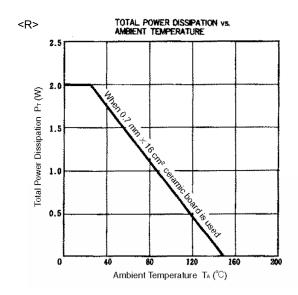


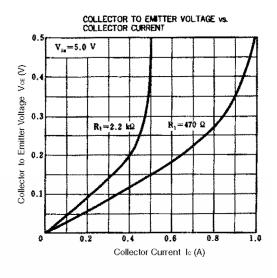
HD1A4A ELECTRICAL CHARACTERISTICS (TA = 25°C)

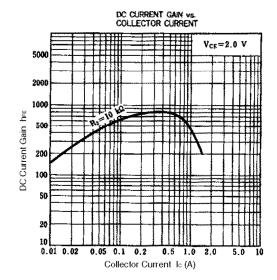
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 60 V, IE = 0			100	nA
DC current gain	h _{FE1} Note	Vce = 2.0 V, Ic = 0.1 A	200	630		1
DC current gain	h _{FE2} Note	Vce = 2.0 V, Ic = 0.5 A	300	780		1
DC current gain	h _{FE3} Note	Vce = 2.0 V, Ic = 1.0 A	200	430		1
Collector saturation voltage	V _{CE(sat)} Note	Ic = 0.7 A, I _B = 7 mA		0.25	0.4	V
Low level input voltage	V _{IL} Note	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \mu\text{A}$		0.5	0.3	V
E-to-B resistance	R ₂		7	10	13	kΩ

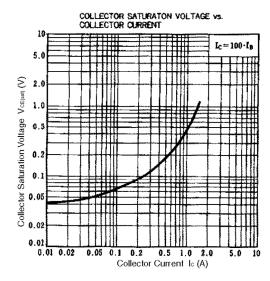
Note PW \leq 350 μ s, duty cycle \leq 2 %

TYPICAL CHARACTERISTICS (TA = 25°C)









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